

QUICKSWITCH® PRODUCTS HIGH-SPEED CMOS 10-BIT BUS SWITCH WITH ACTIVE HIGH AND LOW ENABLES

IDTQS32862

FEATURES:

- Enhanced N channel FET with no inherent diode to Vcc
- Undershoot clamp diodes on all switch and control inputs
- Active low and high enable control
- 25 Ω resistors for low noise
- Available in SOIC and QSOP packages

APPLICATIONS

- Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- Power conservation
- Capacitance reduction and isolation
- Applications requiring Active-High enabling
- Clock gating
- Bus isolation

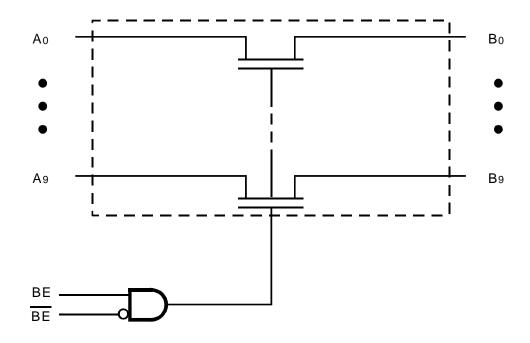
DESCRIPTION:

The QS32862 provides a set of ten high speed CMOS, TTL Compatible bus switches. The switches are controlled by independent active Low enable (BE) and High enable (BE) controls.

The QS32862 includes internal 25Ω series termination resistors to reduce reflection noise in high speed applications. When closed, the switch acts as the source (series) termination for the driver connected to it. The QS32862 is ideal for switching digital buses as well as hot-plugging, hot-docking, and voltage translation.

The QS32862 is characterized for operation at -40°C to +85°C.

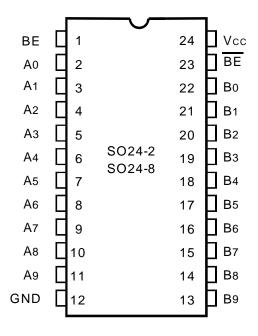
FUNCTIONAL BLOCK DIAGRAM



INDUSTRIAL TEMPERATURE RANGE

FEBRUARY 2000

PIN CONFIGURATION



SOIC/ QSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Description Max.		Unit
VTERM ⁽²⁾	Supply Voltage to Ground	- 0.5 to +7	٧
VTERM ⁽³⁾	DC Switch Voltage Vs	- 0.5 to +7	V
VTERM ⁽³⁾	DC Input Voltage Vin	- 0.5 to +7	V
VAC	AC Input Voltage (pulse width ≤20ns)	-3	V
Іоит	DC Output Current	120	mA
Рмах	Maximum Power Dissipation	0.5	W
Tstg	Storage Temperature	- 65 to +150	°C

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc Terminals.
- 3. All terminals except Vcc.

CAPACITANCE

 $(T_A = +25^{\circ}C, f = 1.0MHz, V_{IN} = 0V, V_{OUT} = 0V)$

Pins	Тур.	Max. ⁽¹⁾	Unit
Control Inputs	3	5	pF
Quickswitch Channels (Switch OFF)	5	7	pF

NOTE:

1. This parameter is guaranteed but not production tested.

PIN DESCRIPTION

Pin Names I/O		Description
BE	I	Active High Bus Enable
BE	I	Active High Bus Enable
A0 – A9	I/O	Bus A
B0 – B9	I/O	Bus B

FUNCTION TABLE(1)

BE	BE	A0 - A9	Function
L	L	Hi-Z	Disconnect
L	Н	Hi-Z	Disconnect
Н	L	B0 – B9	Connect
Н	Н	Hi-Z	Disconnect

NOTE:

- 1. H = HIGH Voltage Level
 - L = LOW Voltage Level
 - Z = High-impedence

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: $T_A = -40^{\circ}C$ to $+85^{\circ}C$, $V_{CC} = 5.0V \pm 10\%$

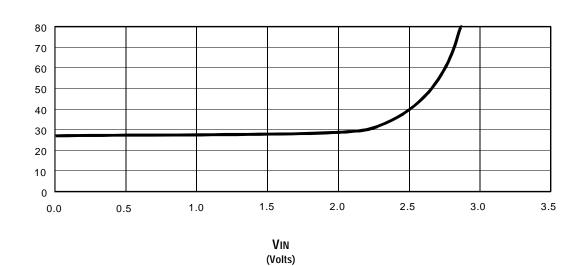
Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2	_	_	٧
VIL	Input LOW Voltage	Guaranteed Logic LOW for Control Pins	_	_	0.8	٧
lin	Input Leakage Current (Control Inputs)	0V ≤ VIN ≤ Vcc	_	±0.01	±1	μΑ
loz	Off-State Current (Hi-Z)	0V ≤ Vouт ≤ Vcc, Switches OFF	_	±0.01	±1	μΑ
Ron	Switch ON Resistance	Vcc = Min., VIN = 0V, ION = 30mA	20	28	40	Ω
Ron	Switch ON Resistance	Vcc = Min., V _{IN} = 2.4V, I _{ON} = 15mA	20	35	48	Ω
VP	Pass Voltage (2)	$VIN = VCC = 5V$, $IOUT = -5\mu A$	3.7	4	4.2	V

NOTES:

- 1. Typical values are at VCC = 5.0V, $TA = 25^{\circ}C$.
- 2. Pass voltage is guaranteed but not production tested.

TYPICAL ON RESISTANCE vs Vin AT Vcc = 5V

RON (ohms)



POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Typ. ⁽²⁾	Max.	Unit
Icco	Quiescent Power Supply Current	Vcc = Max., Vin = GND or Vcc, f = 0	0.2	3	μΑ
Δlcc	Power Supply Current per Control Input HIGH	$Vcc = Max., Vin = 3.4V^{(3)}, f = 0$	_	2.5	mA
ICCD	Dynamic Power Supply Current per MHz ⁽⁴⁾	Vcc = Max., A and B pins open, BE, BE inputs Toggling at 50% Duty Cycle	_	0.25	mA/MHz

NOTES:

- 1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- 2. Typical values are at Vcc = 5.0V, TA = 25°C ambient.
- 3. Per TLL driven input (VIN = 3.4V, control inputs only). A and B pins do not contribute to Δ Icc.
- 4. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $TA = -40^{\circ}C \text{ to } +85^{\circ}C, VCC = 5.0V \pm 10\%$

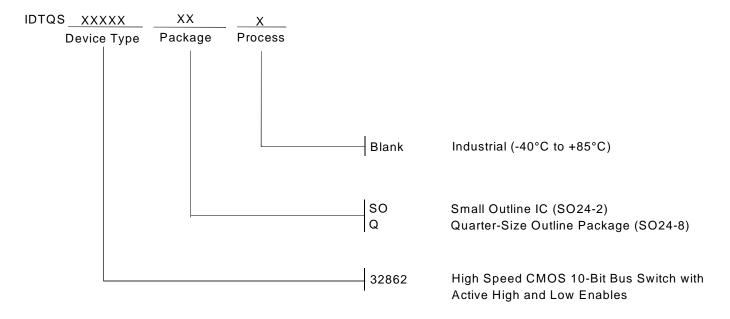
CLOAD = 50pF, RLOAD = 500Ω unless otherwise noted.

Symbol	Parameter	Min. ⁽¹⁾	Тур.	Max.	Unit
tplh	Data Propagation Delay (2,3)			1.25	
t PHL	A to B or B to A	ĺ	ı	1.25	ns
tpzl	Switch Turn-on Delay	1.5		75	
tpzh	BE or BE to A to B	1.5	ĺ	75	ns
tplz	Switch Turn-off Delay (2)	1.5		EE	
tphz	BE or BE to A to B	1.5	_	5.5	ns

NOTES:

- 1. Minimums are guaranteed but not production tested.
- 2. This parameter is guaranteed but not production tested.
- 3. The time constant for the switch alone is of the order of 1.25ns for CL = 50pF. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION





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